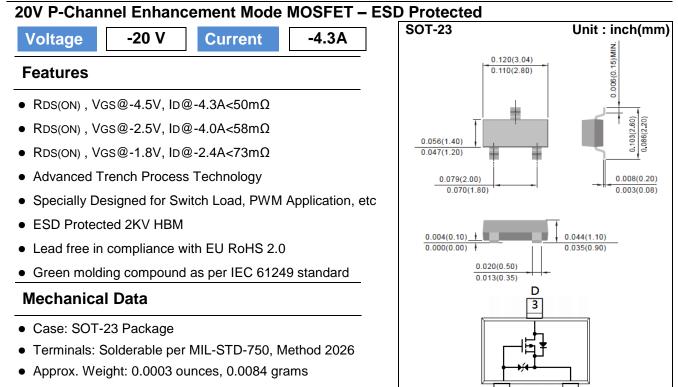
ΡΛΝ	JIT
	SEMI
	CONDUCTOR



Marking: A5AE

Maximum Ratings and Thermal Characteristics ($T_A=25^{\circ}C$ unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS
Drain-Source Voltage		V _{DS}	-20	V
Gate-Source Voltage		V _{GS}	<u>+</u> 8	V
Continuous Drain Current		I _D	-4.3	А
Pulsed Drain Current		I _{DM}	-17.2	А
Power Dissipation	T _a =25°C	P _D	1.25	W
	Derate above 25°C		10	mW/°C
Operating Junction and Storage Temperature Range		T _J ,T _{STG}	-55~150	°C
Typical Thermal resistance - Junction to Ambient (Note 3)		$R_{ extsf{ heta}JA}$	100	°C/W

2

1 G



Electrical Characteristics ($T_A=25^{\circ}C$ unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static		·				
Drain-Source Breakdown Voltage	BV_{DSS}	V _{GS} =0V, I _D =-250uA	-20	-	-	V
Gate Threshold Voltage	V _{GS(th)}	$V_{DS}=V_{GS}$, $I_{D}=-250$ uA	-0.4	-0.55	-1.0	V
Drain-Source On-State Resistance		V _{GS} =-4.5V, I _D =-4.3A	-	42	50	mΩ
	R _{DS(on)}	V _{GS} =-2.5V, I _D =-4.0A	-	49	58	
		V _{GS} =-1.8V, I _D =-2.4A	-	59	73	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =-20V, V _{GS} =0V	-	-0.01	-1	uA
Gate-Source Leakage Current	I _{GSS}	V _{GS} = <u>+</u> 8V, V _{DS} =0V	-	<u>+</u> 6	<u>+</u> 10	uA
Dynamic (Note 5)						
Total Gate Charge	Qg		-	24	-	nC
Gate-Source Charge	Q_gs	V _{DS} =-10V, I _D =-4.3A, V _{GS} =-4.5V ^(Note 1,2)	-	1.5	-	
Gate-Drain Charge	Q_gd		-	2.5	-	
Input Capacitance	Ciss	V _{DS} =-10V, V _{GS} =0V, f=1.0MHZ	-	907	-	pF
Output Capacitance	Coss		-	90	-	
Reverse Transfer Capacitance	Crss		-	70	-	
Turn-On Delay Time	td _(on)		-	45	-	
Turn-On Rise Time	tr	V_{DD} =-10V, I _D =-4.3A, V_{GS} =-4.5V, R_{G} =6 Ω ^(Note 1.2)	-	79	-	ns
Turn-Off Delay Time	td _(off)		-	193	-	
Turn-Off Fall Time	tf	R _G =017	-	826	-	
Drain-Source Diode						
Maximum Continuous Drain-Source					-1.5	_
Diode Forward Current	I _S		-	-	-1.5	A
Diode Forward Voltage	V_{SD}	I _S =-1.0A, V _{GS} =0V	-	0.76	-1.2	V

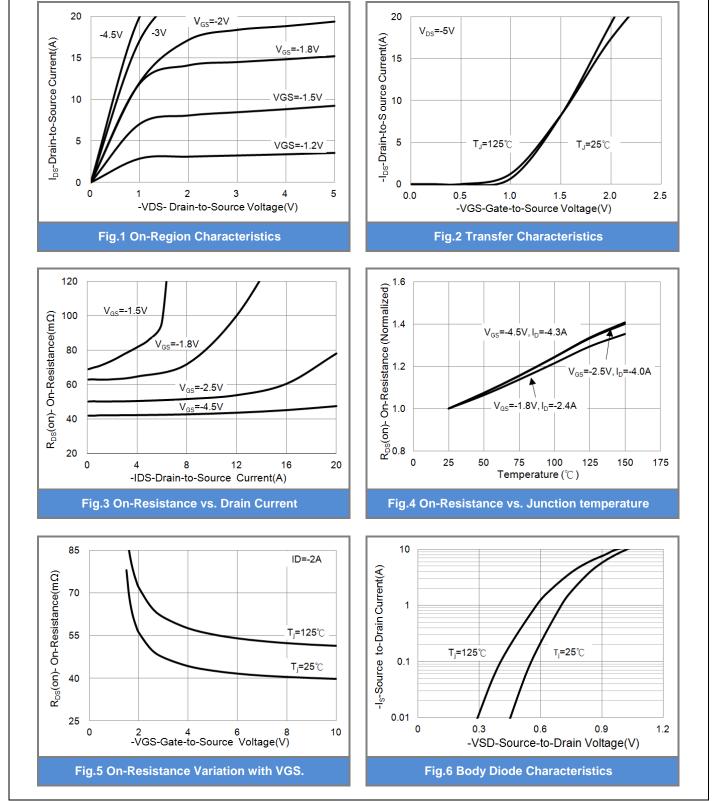
NOTES :

1. Pulse width <300us, Duty cycle <2%

2. Essentially independent of operating temperature typical characteristics.

- 3. R_{0JA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper
- 4. The maximum current rating is package limited
- 5. Guaranteed by design, not subject to production testing.

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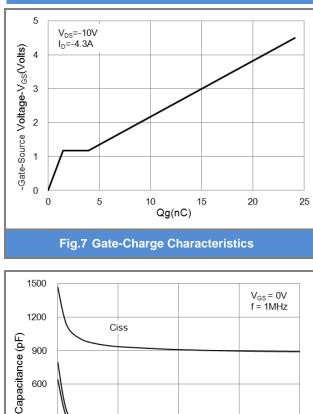




TYPICAL CHARACTERISTIC CURVES



November 26,2019-REV.02



TYPICAL CHARACTERISTIC CURVES

PJA3415AE

SEMI CONDUCTOR

600

300

Crss 0 0

Coss

5

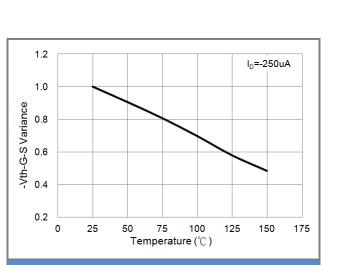
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-VDS-Drain-Source Voltage (V)

Fig.9 Capacitance vs. Drain-Source Voltage.

15

20



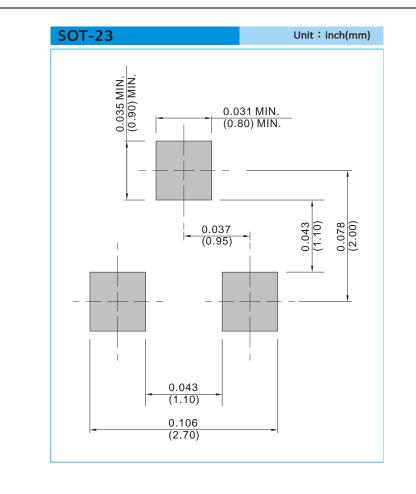




PART NO PACKING CODE VERSION

Part No Packing Code	Package Type	Packing Type	Marking	Version
PJA3415AE_R1_00001	SOT-23	3K pcs / 7" reel	A5AE	Halogen free
PJA3415AE_R2_00001	SOT-23	12K pcs / 13" reel	A5AE	Halogen free

MOUNTING PAD LAYOUT





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